## NSN 5962-01-359-7665

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**Body Length:** 1.111 inches **Body Width:** Between 0.350 inches and 0.410 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 495.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 6625-01-260-2936 **Features Provided:** Hermetically sealed and burn in and monolithic and static operation **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** D-7 mil-m-38510 **Current Rating Per Characteristic:** 90.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** 6.00 input picofarads and 7.00 output picofarads **Time Rating Per Chacteristic:** 35.00 nanoseconds delay **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 

22 printed circuit

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Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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